U.S. Ser. No. 10/663,531 Our File: MIT 9983

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

APPLICANT: Tuller et al.

**GROUP**: 2815

**SERIAL NO:** 

10/663,531

**EXAMINER**: M. Landau

FILED:

September 16, 2003

FOR:

METHOD FOR P-TYPE DOPING OF WIDE BAND GAP

**OXIDE SEMICONDUCTORS** 

Commissioner of Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

## **AMENDMENT**

In response to the Office Action mailed July 25, 2007, please amend the above-identified application as follows: